

7-Unit 400mA Darlington Transistor Array

IR2C17/IR2C17N

T-43-25

IR2C17/IR2C17N 7-Unit 400mA Darlington Transistor Array

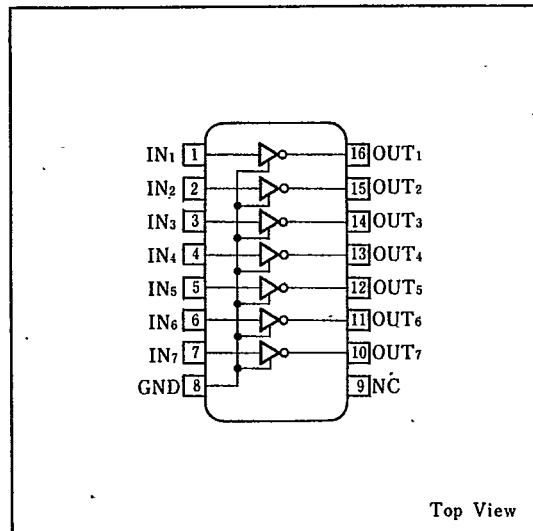
Description

The IR2C17/IR2C17N is a 7-circuit driver. Input characteristics are specified to match the SHARP one-chip microcomputer SM550 series and CMOS logic IC.

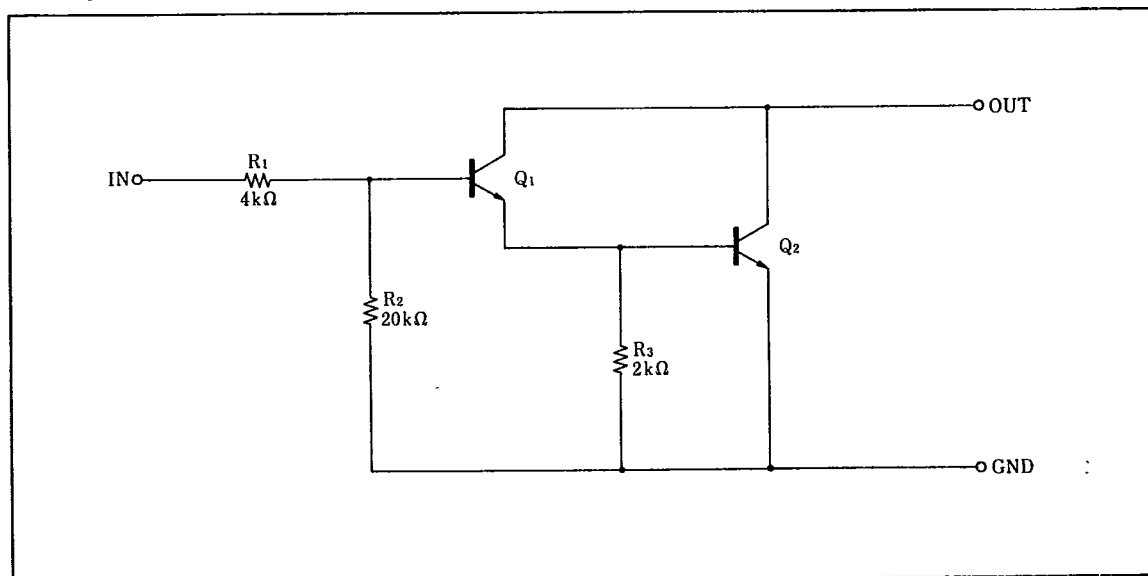
Features

1. High output current $I_{OUT}=400\text{mA}$ (MAX.)
2. High output breakdown voltage
 $BV_{CED}=45\text{V}$ (MAX.)
3. Directly driven by CMOS output
4. Darlington construction
5. 16-pin dual-in-line package (IR2C17)
16-pin small-outline package (IR2C17N)

Pin Connections



Equivalent Circuit



SHARP

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■ Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	V_{CC}		45	V
Output current *1	I_{OUT}	Each circuit	400	mA
Input voltage	V_{IN}		45	V
Collector-emitter breakdown voltage	BV_{CEO}		45	V
Power dissipation	P_D	$T_a \leq 25^\circ\text{C}$	IR2C17 650	mW
			IR2C17N 450	
P_D derating ratio	$\Delta P_D/^\circ\text{C}$	$T_a > 25^\circ\text{C}$	IR2C17 6.5	mW/°C
			IR2C17N 3.6	
Operating temperature	T_{opr}		-25 ~ +75	°C
Storage temperature	T_{stg}		-55 ~ +150	°C

*1 Duty cycle 7% or less, repetitive frequency: 10Hz or more (Input voltage: 5.5V)

■ Recommended Operating Conditions

Parameter	Symbol	Condition	Rating	Unit
Output voltage	V_{CEO}		45	V
Output current	I_{OUT}	at 10% duty	0 ~ 400	mA
		at 50% duty	0 ~ 150	

* Repetitive frequency: 10Hz or more.

■ Electrical Characteristics

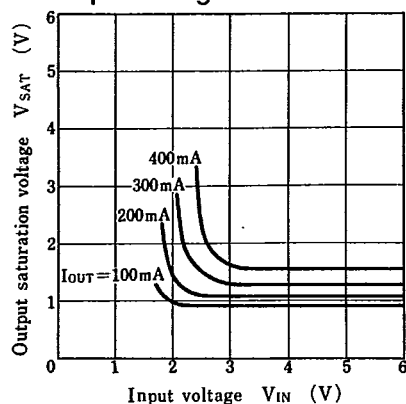
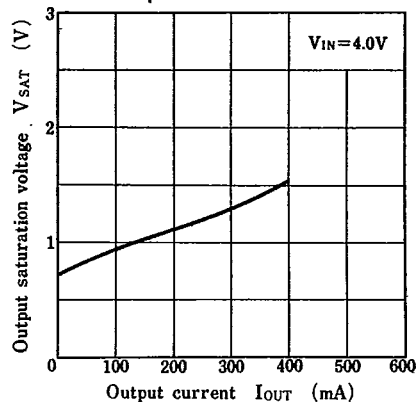
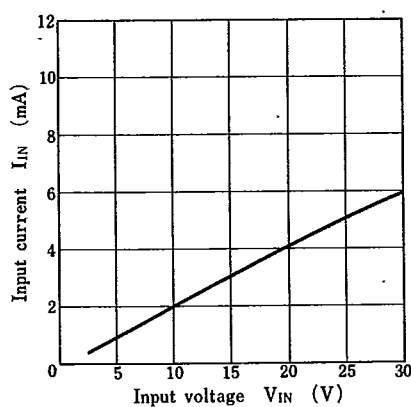
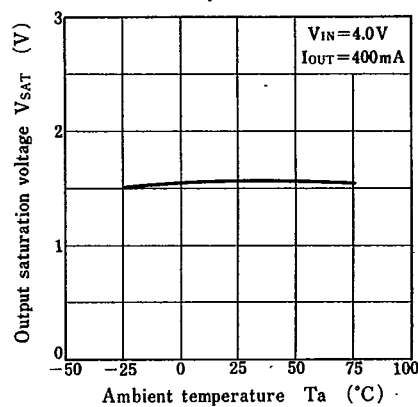
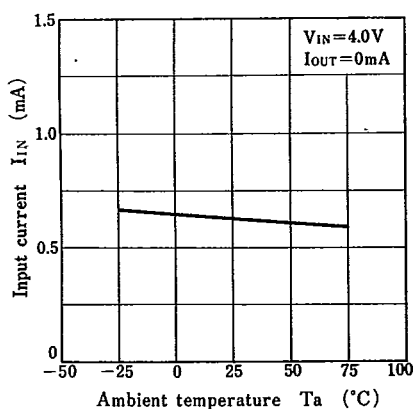
(Ta = -25 ~ +75°C)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Supply voltage	V_{CC}				45	V
ON-State input current	$I_{I\ ON}$	$V_{IN}=5.5\text{V}, I_{OUT}=0\text{mA}$		1	1.5	mA
ON-State output voltage	$V_{O\ ON1}$	$V_{IN}=4.0\text{V}, I_{OUT}=400\text{mA}$			2.2	V
	$V_{O\ ON2}$	$V_{IN}=4.0\text{V}, I_{OUT}=200\text{mA}$			1.4	
OFF-State output current	$I_{O\ OFF}$	$V_{IN}=0\text{V}, V_{CEO}=45\text{V}$			100	μA
DC current amplitude	h_{FE}	$V_{CEO}=2.5\text{V}, I_{OUT}=300\text{mA}$	1,000			
Input "High" voltage	V_{IH}		4			V
Input "Low" voltage	V_{IL}				0.4	V

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Electrical Characteristic Curves (Unless otherwise specified, $T_a = 25^\circ\text{C}$)Output saturation voltage—
Input voltage CharacteristicsOutput saturation voltage—
Output current CharacteristicsInput current— Input voltage
CharacteristicsOutput saturation voltage—
Ambient temperature CharacteristicsInput current—Ambient temperature
Characteristics

Output current—Duty cycle Characteristics

